



NCE N-Channel Enhancement Mode Power MOSFET

Description

The NCE6020AK uses advanced trench technology and design to provide excellent $R_{DS(ON)}$ with low gate charge. It can be used in a wide variety of applications.

General Features

- V_{DS} =60V,I_D =20A
 R_{DS(ON)} <35mΩ @ V_{GS}=10V
- High density cell design for ultra low Rdson
- Fully characterized avalanche voltage and current
- Good stability and uniformity with high E_{AS}
- Excellent package for good heat dissipation
- Special process technology for high ESD capability

Application

- Power switching application
- Hard switched and high frequency circuits
- Uninterruptible power supply

100% UIS TESTED!

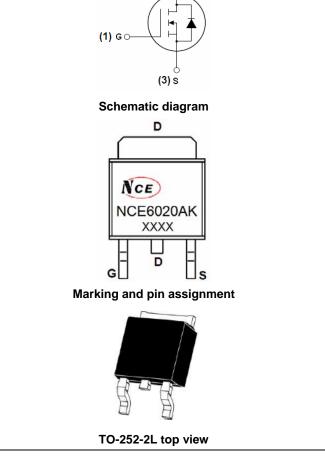
100% ΔVds TESTED!

Package Marking and Ordering Information

Device Marking	Device	Device Package	Reel Size	Tape width	Quantity
NCE6020AK	NCE6020AK	TO-252-2L	-	-	-

Absolute Maximum Ratings (Tc=25°C unless otherwise noted)

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	Vds	60	V
Gate-Source Voltage	Vgs	±20	V
Drain Current-Continuous	Ι _D	20	А
Drain Current-Continuous(T _C =100℃)	I _D (100℃)	14	А
Pulsed Drain Current	I _{DM}	60	А
Maximum Power Dissipation	PD	45	W
Derating factor		0.3	W/℃
Single pulse avalanche energy (Note 5)	E _{AS}	72	mJ
Operating Junction and Storage Temperature Range	T _J ,T _{STG}	-55 To 175	°C



(2) D





Thermal Characteristic

Thermal Resistance, Junction-to-CaseNote 2)R _{0JC} 3.3°C/W

Electrical Characteristics (T_c=25 $^{\circ}$ Cunless otherwise noted)

BV _{DSS}	V _{GS} =0V Ι _D =250μΑ	1			
	V _{GS} =0V I _D =250µA				
I _{DSS}		60	-	-	V
	V _{DS} =60V,V _{GS} =0V	-	-	1	μA
I _{GSS}	V _{GS} =±20V,V _{DS} =0V	-	-	±100	nA
V _{GS(th)}	V _{DS} =V _{GS} ,I _D =250µA	1.2	1.6	2.5	V
R _{DS(ON)}	V _{GS} =10V, I _D =20A	-	27	35	mΩ
g fs	V _{DS} =5V,I _D =5A	11	-	-	S
			•		
C _{lss}		-	500	-	PF
C _{oss}		-	60	-	PF
C _{rss}	F=1.0MHZ	-	25	-	PF
		•			
t _{d(on)}		-	5	-	nS
tr	V _{DD} =30V,I _D =2A,R _L =6.7Ω	-	2.6	-	nS
t _{d(off)}	V _{GS} =10V,R _G =3Ω	-	16.1	-	nS
t _f		-	2.3	-	nS
Qg)/ 00)//L 4.5A	-	47		nC
Q _{gs}		-	6		nC
Q _{gd}	V _{GS} =10V	-	14		nC
		•			
V _{SD}	V _{GS} =0V,I _S =20A	-		1.2	V
I _S		-	-	20	А
t _{rr}	TJ = 25°C, IF =20A	-	35	-	nS
Qrr	di/dt = 100A/µs ^(Note3)	-	53	-	nC
t _{on}	Intrinsic turn-on time is negligible (turn-on is dominated by LS+LD				y LS+LD)
	IGSS VGS(th) RDS(ON) gFS Clss Coss Crss td(on) tr dd(off) tf Qg Qgs Qgd VSD Is trr Qrr	$\begin{tabular}{ c c c c c } \hline I_{GSS} & V_{GS} = \pm 20V, V_{DS} = 0V \\ \hline V_{GS(th)} & V_{DS} = V_{GS}, I_D = 250 \mu A \\ \hline R_{DS(ON)} & V_{GS} = 10V, I_D = 20A \\ \hline g_{FS} & V_{DS} = 5V, I_D = 5A \\ \hline \hline C_{ISS} & V_{DS} = 30V, V_{GS} = 0V, \\ \hline C_{\sigmass} & F = 1.0 MHz \\ \hline \hline C_{rss} & V_{DD} = 30V, I_D = 2A, R_L = 6.7\Omega \\ \hline t_{d(off)} & V_{DD} = 30V, I_D = 2A, R_L = 6.7\Omega \\ \hline t_{d(off)} & V_{DS} = 10V, R_G = 3\Omega \\ \hline t_{f} & V_{DS} = 10V, R_G = 3\Omega \\ \hline t_{f} & V_{DS} = 30V, I_D = 4.5A, \\ \hline Q_{gg} & V_{DS} = 30V, I_D = 4.5A, \\ \hline V_{GS} = 10V \\ \hline Q_{gd} & V_{GS} = 0V, I_S = 20A \\ \hline I_S & I_T & TJ = 25^{\circ}C, IF = 20A \\ \hline d_{I}/dt = 100A/\mu s^{(Note3)} \\ \hline \end{tabular}$	$\begin{array}{ c c c c c c } I_{GSS} & V_{GS} = \pm 20V, V_{DS} = 0V & - \\ \hline & V_{GS}(th) & V_{DS} = V_{GS}, I_D = 250 \mu A & 1.2 \\ \hline & R_{DS}(ON) & V_{GS} = 10V, I_D = 20A & - \\ \hline & g_{FS} & V_{DS} = 5V, I_D = 5A & 11 \\ \hline & & & \\ \hline & C_{ISS} & & V_{DS} = 30V, V_{GS} = 0V, & - \\ \hline & C_{rss} & & F = 1.0MHz & - \\ \hline & C_{rss} & & & & \\ \hline & & & & \\ \hline & t_{d}(on) & & & & \\ \hline & t_{r} & V_{DD} = 30V, I_D = 2A, R_L = 6.7\Omega & - \\ \hline & t_{d}(off) & V_{GS} = 10V, R_G = 3\Omega & - \\ \hline & t_{f} & & & & \\ \hline & Q_{gg} & & V_{DS} = 30V, I_D = 4.5A, & - \\ \hline & Q_{gg} & & V_{GS} = 10V & - \\ \hline & V_{SD} & V_{GS} = 0V, I_S = 20A & - \\ \hline & I_S & & & - \\ \hline & t_{rr} & TJ = 25^{\circ}C, IF = 20A & - \\ \hline & Q_{rr} & di/dt = 100A/\mu s^{(Note3)} & - \\ \hline \end{array}$	$\begin{array}{ c c c c c c c c } & V_{GS}=\pm 20V, V_{DS}=0V & - & - & \\ \hline V_{GS(th)} & V_{DS}=V_{GS}, I_{D}=250 \mu A & 1.2 & 1.6 \\ \hline R_{DS(ON)} & V_{GS}=10V, I_{D}=20A & - & 27 \\ \hline g_{FS} & V_{DS}=5V, I_{D}=5A & 11 & - & \\ \hline \hline C_{ISS} & & & & & & & \\ \hline C_{OSS} & & & & & & & & \\ \hline C_{rss} & & & & & & & & \\ \hline C_{rss} & & & & & & & & \\ \hline & V_{DS}=30V, V_{GS}=0V, & & & & & & & \\ \hline & & & & & & & & & \\ \hline C_{rss} & & & & & & & & \\ \hline & & & & & & & & \\ \hline & & & &$	$\begin{tabular}{ c c c c c c } \hline I_{GSS} & V_{GS}=\pm 20V, V_{DS}=0V & - & - & \pm 100 \\ \hline V_{GS(th)} & V_{DS}=V_{GS}, I_{D}=250 \mu A & 1.2 & 1.6 & 2.5 \\ \hline R_{DS(ON)} & V_{GS}=10V, I_{D}=20A & - & 27 & 35 \\ \hline g_{FS} & V_{DS}=5V, I_{D}=5A & 11 & - & - \\ \hline \hline C_{Iss} & V_{DS}=30V, V_{GS}=0V, & - & 60 & - \\ \hline C_{rss} & F=1.0MHz & - & 60 & - \\ \hline C_{rss} & F=1.0MHz & - & 25 & - \\ \hline t_{d(on)} & & & & \\ \hline t_{d(on)} & & & & & \\ \hline t_{d(off)} & V_{DD}=30V, I_{D}=2A, R_{L}=6.7\Omega & - & 2.6 & - \\ \hline t_{d(off)} & V_{GS}=10V, R_{G}=3\Omega & - & 16.1 & - \\ \hline c_{Qg} & & V_{DS}=30V, I_{D}=4.5A, & & & \\ \hline Q_{gd} & V_{DS}=30V, I_{D}=4.5A, & & & & \\ \hline V_{SD} & V_{GS}=10V & & & & & \\ \hline \hline V_{SD} & V_{GS}=0V, I_{S}=20A & - & & & 1.2 \\ \hline I_{S} & & & & & - & 20 \\ \hline t_{rr} & TJ = 25^{\circ}C, IF = 20A & - & & & 35 & - \\ \hline Q_{rr} & di/dt = 100A/\mu s^{(Note3)} & - & 53 & - \\ \hline \end{tabular}$

Notes:

- 1. Repetitive Rating: Pulse width limited by maximum junction temperature.
- **2.** Surface Mounted on FR4 Board, $t \le 10$ sec.
- **3.** Pulse Test: Pulse Width \leq 300µs, Duty Cycle \leq 2%.
- 4. Guaranteed by design, not subject to production
- 5. EAS condition: Tj=25 $^{\circ}$ C, VDD=30V, VG=10V, L=0.5mH, Rg=25 Ω

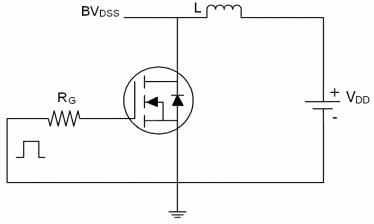


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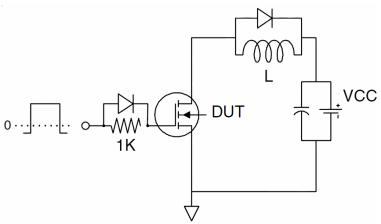




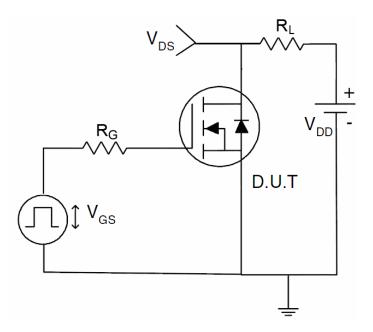
Test Circuit 1) E_{AS} test Circuit



2) Gate charge test Circuit



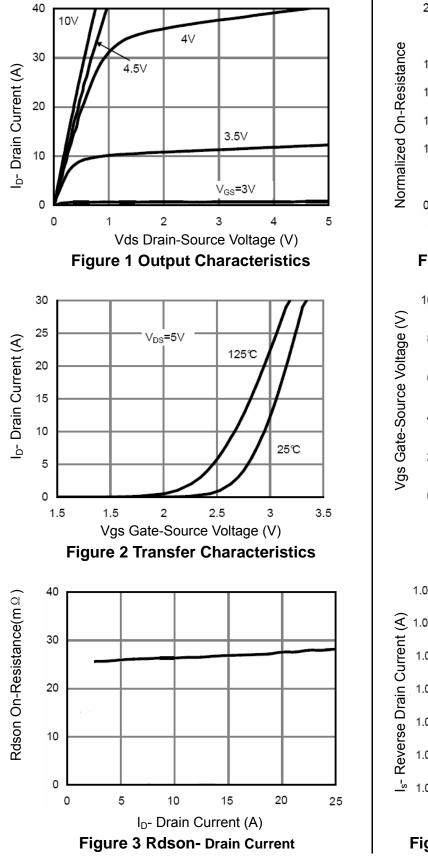
3) Switch Time Test Circuit

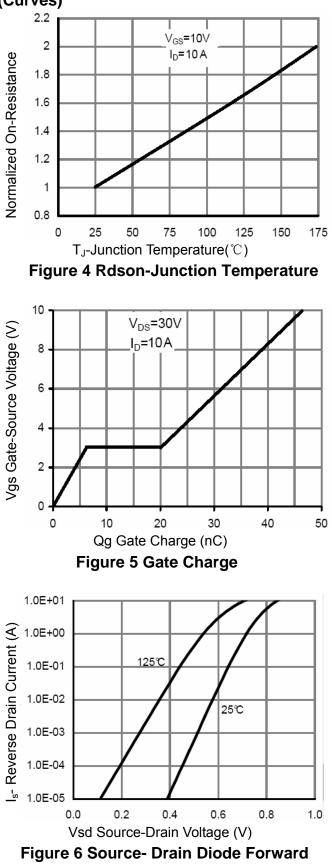










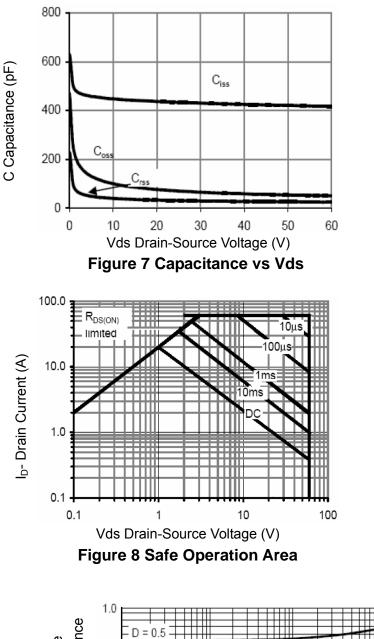




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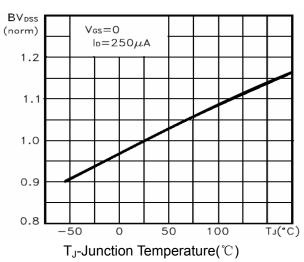


Figure 9 BV_{DSS} vs Junction Temperature

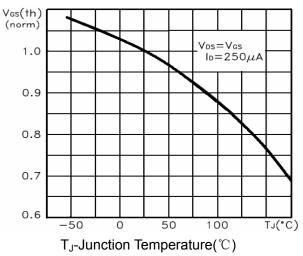
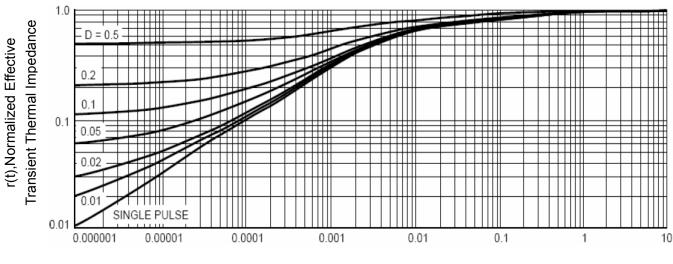
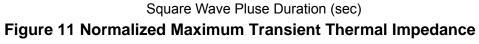


Figure 10 V_{GS(th)} vs Junction Temperature



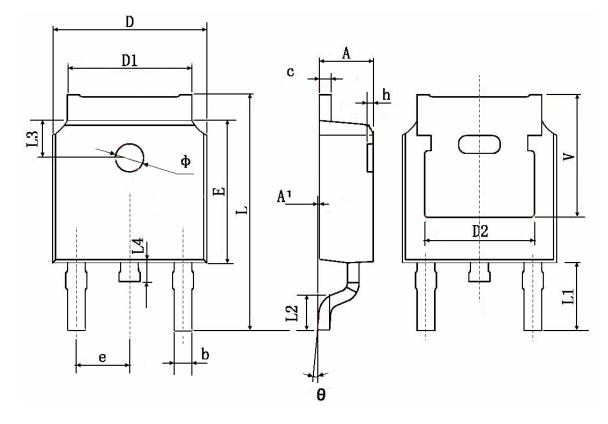




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TO-252 Package Information



Symbol	Dimensions In Millimeters		Dimensions In Inches		
	Min.	Max.	Min.	Max.	
А	2.200	2.400	0.087	0.094	
A1	0.000	0.127	0.000	0.005	
b	0.660	0.860	0.026	0.034	
С	0.460	0.580	0.018	0.023	
D	6.500	6.700	0.256	0.264	
D1	5.100	5.460	0.201	0.215	
D2	0.483 TYP.		0.190 TYP.		
E	6.000	6.200	0.236	0.244	
е	2.186	2.386	0.086	0.094	
L	9.800	10.400	0.386	0.409	
L1	2.900 TYP.		0.114 TYP.		
L2	1.400	1.700	0.055	0.067	
L3	1.600 TYP.		0.063 TYP.		
L4	0.600	1.000	0.024	0.039	
Φ	1.100	1.300	0.043	0.051	
θ	0°	8°	0°	8°	
h	0.000	0.300	0.000	0.012	
V	5.350) TYP.	0.211 TYP.		







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